

FMMT415TC Datasheet



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DiGi Electronics Part Number FMMT415TC-DG

Manufacturer Diodes Incorporated

Manufacturer Product Number FMMT415TC

Description TRANS NPN 100V 0.5A SOT23-3

Detailed Description Bipolar (BJT) Transistor NPN - Avalanche Mode 100

V 500 mA 40MHz 330 mW Surface Mount SOT-23-3



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
FMMT415TC	Diodes Incorporated
Series:	Product Status:
	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
NPN - Avalanche Mode	500 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
100 V	500mV @ 1mA, 10mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA (ICBO)	25 @ 10mA, 10V
Power - Max:	Frequency - Transition:
330 mW	40MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	SOT-23-3
Base Product Number:	
FMMT415	

Environmental & Export classification

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	





NPN AVALANCHE TRANSISTOR IN SOT23

Features

- Avalanche Transistor
- 60A Peak Avalanche Current (Pulse width = 20ns)
- BV_{CES} > 260V (415) & 320V (417)
- BV_{CEO} > 100V
- Specifically designed for Avalanche mode operation
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Description

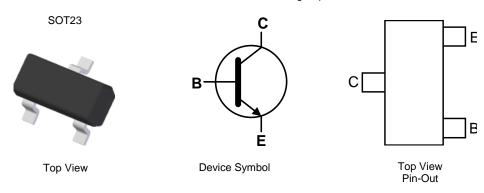
The FMMT415/417 are NPN silicon planar bipolar transistors designed for operating in avalanche mode. Tight process control and low inductance packaging combine to produce high-current pulses with fast edges.

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)

Applications

- Laser Diode Drivers for Ranging and Measurement (LIDAR)
- Radar Systems
- Fast Edge Switch Generator
- High Speed Pulse Generators



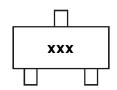
Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT415TD	AEC-Q101	415	7	8	500
FMMT417TD	AEC-Q101	417	7	8	500

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



xxx = Product Type Marking Code (See Ordering Information)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	FMMT415	FMMT417	Unit
Collector-Base Voltage	V _{CBO}	260	320	V
Collector-Emitter Voltage	V _{CES}	260	320	V
Collector-Emitter Voltage	V _{CEO}	100	100	V
Emitter-Base Voltage	V _{EBO}	6		V
Continuous Collector Current	Ic	500		mA
Peak Collector Current (Pulse Width = 20ns)	I _{CM}	60		Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_{D}	500	mW
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	250	°C/W
Thermal Resistance, Junction to Lead	(Note 6)	$R_{ heta JL}$	197	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

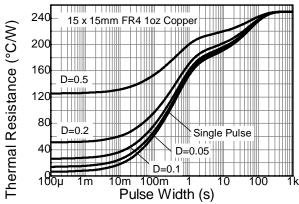
^{5.} For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

Thermal resistance from junction to solder-point (at the end of the collector lead).

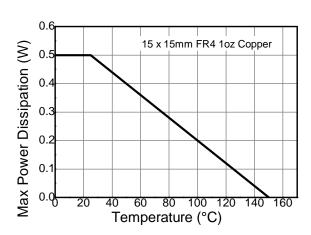
^{7.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.



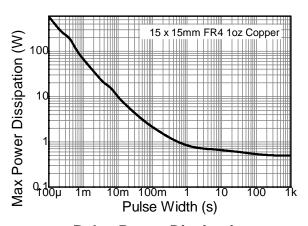
Thermal Characteristics and Derating Information



Transient Thermal Impedance



Derating Curve



Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

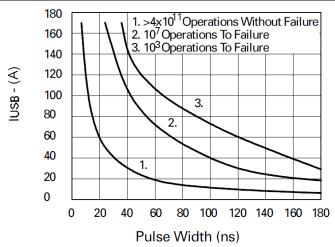
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	FMMT415	BV _{CES}	260	_	_	V	I _C = 1mA T _J = -55 to +150°C
	FMMT417		320	_	_		I _C = 1mA
Collector-Emitter Breakdown Voltage (Not	e 8)	BV _{CEO}	100	_	_	V	$I_C = 100 \mu A$
Emitter-Base Breakdown Voltage		BV _{EBO}	6	_	_	V	$I_E = 100 \mu A$
Collector Cutoff Current		I _{CBO}	_	_	100 10	nΑ μΑ	V _{CB} = 180V V _{CB} = 180V, T _J = +100°C
Emitter Cutoff Current		I _{EBO}	_	_	100	nA	$V_{EB} = 4V$
Static Forward Current Transfer Ratio (Note 8)		h _{FE}	25	_	_	_	$I_C = 10mA, V_{CE} = 10V$
Collector-Emitter Saturation Voltage (Note 8)		V _{CE(sat)}	_	_	500	mV	$I_C = 10\text{mA}$, $I_B = 1\text{mA}$
Base-Emitter Saturation Voltage (Note 8)		V _{BE(sat)}	_	_	900	mV	$I_C = 10\text{mA}$, $I_B = 1\text{mA}$
Pulsed Current in Second Breakdown		I _{USB}	_	25 35	_	A A	$V_C = 200V, C_{CE} = 620pF$ $V_C = 250V, C_{CE} = 620pF$
Collector-Emitter Inductance		L _{ce}	_	2.5	_	nΗ	Standard SOT23 leads
Output Capacitance		C _{obo}	_	_	8	pF	V _{CB} = 20V, I _E = 0 f = 100MHz
Transition Frequency		f _T	40	_	_	MHz	V _{CE} = 20V, I _C = 10mA, f = 20MHz

Note:

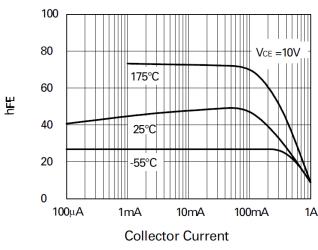
8. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



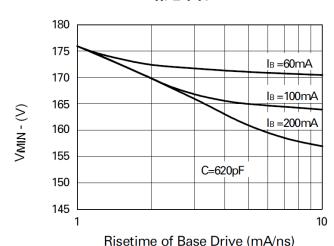
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



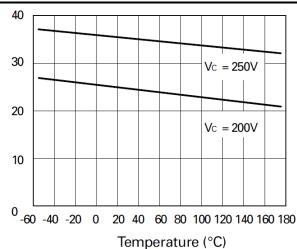
Maximum Avalanche Current v Pulse Width



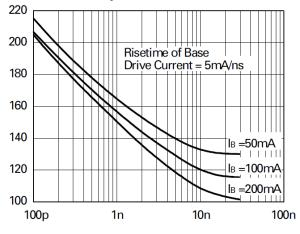
hfe v IC



Minimum starting voltage as a function of drive current

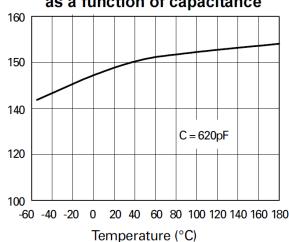


IUSB v Temperature for the specified conditions



Collector-Emitter Capacitance (F)

Minimum starting voltage as a function of capacitance

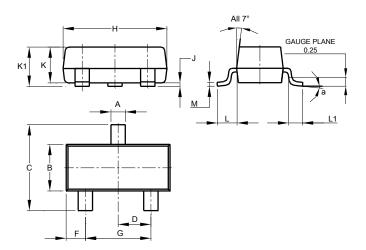


Minimum starting voltage as a function of temperature



Package Outline Dimensions

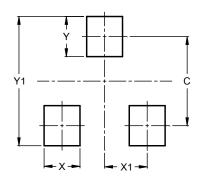
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Υ	0.9
Y1	2.9

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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